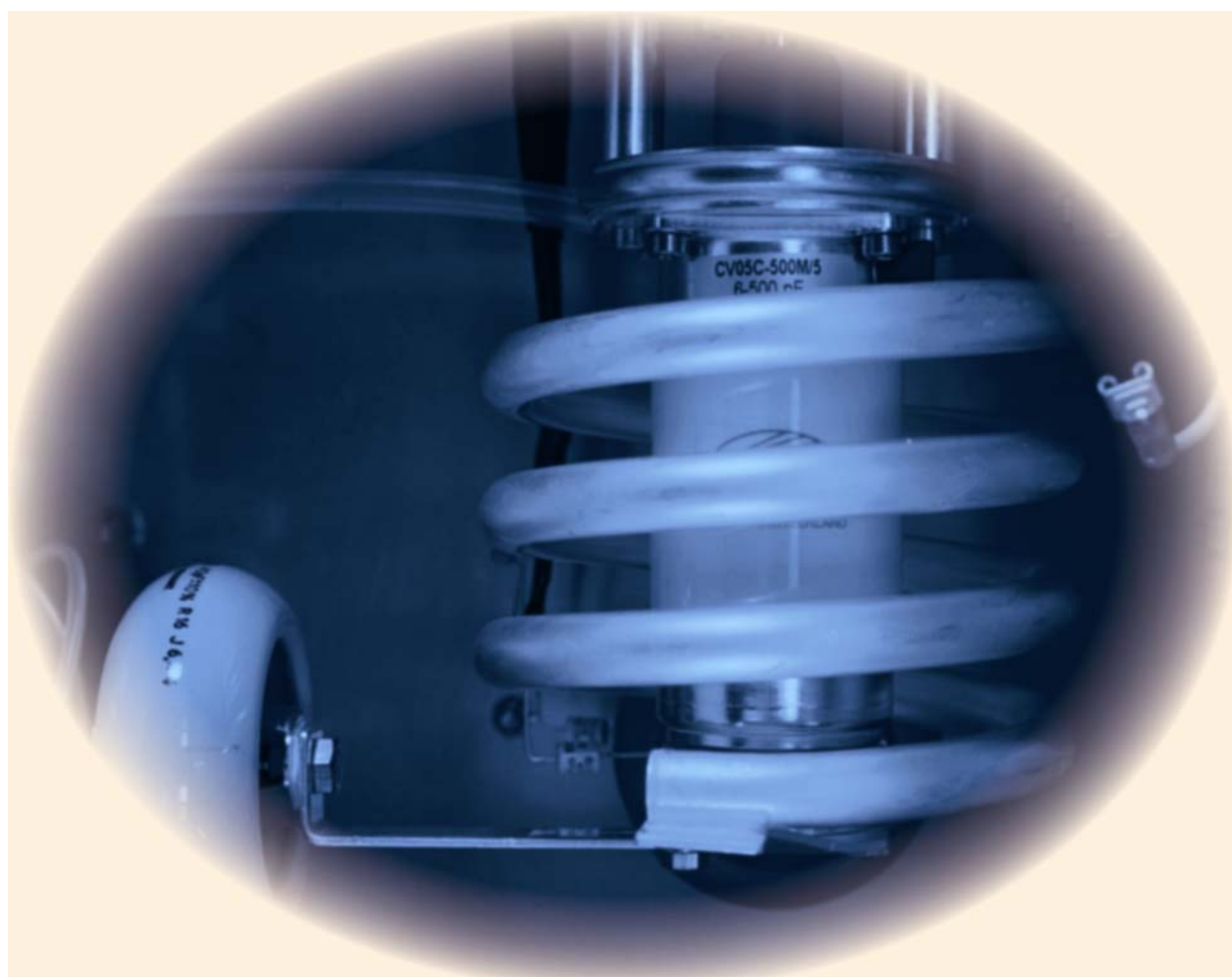




THINKING AHEAD



## Aurion's Radio Frequency Workshop





## Contents

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### 1 Plasma process technology

- 1 Ionization and plasma
- 2 Plasma cleaning
- 3 Plasma activation
- 4 DC - sputtering
- 5 RF - sputtering
  - 5.1 RF - generator
  - 5.2 Matchbox
  - 5.3 Self - bias
- 6 Magnetron - sputtering
- 7 Etching
- 8 Reactive processes
  - 8.1 Reactive sputtering
  - 8.2 Reactive ion etching (RIE)
- 9 PECVD

### 2 Radio frequency components

- 1 Materials
  - 1.1 Insulators
  - 1.2 Conductors
- 2 Capacitors
  - 2.1 Ceramic capacitors
  - 2.2 Vacuum capacitors
  - 2.3 Capacitor drives
  - 2.4 Couplings
- 3 Coils
- 4 Housings
- 5 RF - sealing / contacts
  - 5.1 Contact strips
  - 5.2 Grids / honeycomb chimney
  - 5.3 Viewing ports
  - 5.4 Connectors
  - 5.5 Vacuum relays
  - 5.6 Pneumatic switches
- 6 Cables and conductors
  - 6.1 Connections
  - 6.2 Contacts



- 6.3 Distances and leakage paths
- 6.4 Insulators
- 7 Housing and shielding
  - 7.1 Doors and lids
- 8 Temperature and cooling
  - 8.1 Isolation paths

### **3 Impedance - matching**

- 1 Current and voltage
  - 1.1 DC: Direct current, direct voltage, resistance
  - 1.2 RF: Alternating current, alternating voltage, resistance
  - 1.3 RF: Capacitors and inductivities
- 2 Inner resistance and load resistance
  - 2.1 DC - electrode
  - 2.2 RF - electrode
  - 2.3 Pointer diagram
  - 2.4 Real and reactive power
- 3 Matching circuits
- 4 Smith-Chart
- 5 Waves on conductors
  - 5.1 Matching
  - 5.2 Mismatch
  - 5.3 Forward and reflected power

### **4 Measurements and trouble shooting**

- 1 Set-up RF - generator
- 2 Set-up matchbox
- 3 Measurement interfering radiation
- 4 Measurement with the probe
- 5 Measurement with the oscilloscope
- 6 RF - start-up
  - 6.1 Preparation
  - 6.2 Igniting plasma
- 7 Trouble shooting
  - 7.1 No plasma ignition
  - 7.2 Reflected power too high